NSN 5961-01-026-2570

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View Online at https://aerobasegroup.com/nsn/5961-01-026-2570 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches Overall Diameter: Between 0.209 inches and 0.230 inches **Internal Configuration:** Junction contact **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 collector to base voltage, dc and 15.0 collector to emitter voltage/static/base open and 4.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 200.0 milliwatts small-signal input power, common-collector absolute **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 80009-151-0442-00 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: